EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	10471	(257/59.ccls. or 257/66. ccls. or 257/72.ccls. or 257/E27.111.ccls. or 257/E29.278.ccls. or 257/E29.293.ccls.)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/03/05 15:52
L2	13271	(257/59.ccls. or 257/66. ccls. or 257/72.ccls. or 257/E27.111.ccls. or 257/E29.278.ccls. or 257/E29.293.ccls.) samd ((channel near2 (region or portion or area) same (wire or wiring or metal or interconnect or interconnection) same (tft or (thin near film near transistor)))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/03/05 15:53
L3	12079	(257/59.ccls. or 257/66. ccls. or 257/72.ccls. or 257/E27.111.ccls. or 257/E29.278.ccls. or 257/E29.293.ccls.) samd ((channel near2 (region or portion or area) same (wire or wiring or metal or interconnect or interconnection) same (tft or (thin near film near transistor)) same (gate adj electrode))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/03/05 15:53
L4	0	(257/59.ccls. or 257/66. ccls. or 257/72.ccls. or 257/E27.111.ccls. or 257/E29.278.ccls. or 257/E29.293.ccls.) same ((channel near2 (region or portion or area) same (wire or wiring or metal or interconnect or interconnection) same (tft or (thin near film near transistor)) same (gate adj electrode))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/03/05 15:53

L5	1127	(257/59.ccls. or 257/66. ccls. or 257/72.ccls. or 257/E27.111.ccls. or 257/E29.278.ccls. or 257/E29.293.ccls.) and ((channel near2 (region or portion or area)) same (wire or wiring or metal or interconnect or interconnection) same (tft or (thin near film near transistor)) same (gate adj electrode))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/03/05 15:53
L6	262	(257/59.ccls. or 257/66. ccls. or 257/72.ccls. or 257/E27.111.ccls. or 257/E29.278.ccls. or 257/E29.293.ccls.) and ((channel near2 (region or portion or area)) same (wire or wiring or metal or interconnect or interconnection) same (tft or (thin near film near transistor)) same (gate adj electrode) same (drive or driving or driver))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/03/05 15:54
L7	178	(257/59.ccls. or 257/66. ccls. or 257/72.ccls. or 257/E27.111.ccls. or 257/E29.278.ccls. or 257/E29.293.ccls.) and ((channel near2 (region or portion or area)) same (wire or wiring or metal or interconnect or interconnection) same (tft or (thin near film near transistor)) same (gate adj electrode) same (drive or driving or driver) same pixel)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/03/05 15:54

L8	37	(257/59.ccls. or 257/66. ccls. or 257/72.ccls. or 257/E27.111.ccls. or 257/E29.278.ccls. or 257/E29.293.ccls.) and ((channel near2 (region or portion or area)) same (wire or wiring or metal or interconnect or interconnection) same (tft or (thin near film near transistor)) same (gate adj electrode) same (drive or driving or driver) same pixel). clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/03/05 15:55
L9	7	(257/59.ccls. or 257/66. ccls. or 257/72.ccls. or 257/E27.111.ccls. or 257/E29.278.ccls. or 257/E29.293.ccls.) and ((channel near2 (region or portion or area)) same (gate near2 (wire or wiring or metal or interconnect or interconnection)) same (tft or (thin near film near transistor)) same (gate adj electrode) same (drive or driving or driver) same pixel). clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/03/05 15:56
L10	36	(257/59.ccls. or 257/66. ccls. or 257/72.ccls. or 257/E27.111.ccls. or 257/E29.278.ccls. or 257/E29.293.ccls.) and ((channel near2 (region or portion or area)) same (gate near2 (wire or wiring or metal or interconnect or interconnection)) same (tft or (thin near film near transistor)) same (gate adj electrode) same (drive or driving or driver) same pixel)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/03/05 15:58
L11	10	09/544801	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/03/05 15:59

L12	8	("20070224791" | "6171910" | "6271573" | "6576926").PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/03/05 16:12
L13	0	(257/59.ccls. or 257/66.ccls. or 257/72.ccls. or 257/E27.111.ccls. or 257/E29.278.ccls. or 257/E29.293.ccls.) and (gate same electrode same (storage near capacitor))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/03/05 16:13
L14	1806	(257/59.ccls. or 257/66.ccls. or 257/72.ccls. or 257/E27.111.ccls. or 257/E29.278.ccls. or 257/E29.293.ccls.) and (gate same electrode same (storage near capacitor))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/03/05 16:13
L15	481	(257/59.ccls. or 257/66.ccls. or 257/72.ccls. or 257/E27.111.ccls. or 257/E29.278.ccls. or 257/E29.293.ccls.) and (gate same electrode same (storage near capacitor) same ((conductive or conducting or metal or interconnect or interconnection or wiring) near layer))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/03/05 16:14
L16	53	(257/59.ccls. or 257/66.ccls. or 257/72.ccls. or 257/E27.111.ccls. or 257/E29.278.ccls. or 257/E29.293.ccls.) and ((gate near (wire or wiring or metal or interconnect or interconnection)) same electrode same (storage near capacitor) same ((conductive or conducting or metal or interconnect or interconnection) near layer))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/03/05 16:14

L17	25	(257/59.ccls. or 257/66. ccls. or 257/72.ccls. or 257/E27.111.ccls. or 257/E29.278.ccls. or 257/E29.293.ccls.) and ((gate near (wire or wiring or metal or interconnect or interconnection)) same electrode same (storage near capacitor) same (((first or second or third or upper or lower or top or bottom) near2 (conductive or conducting or metal or interconnect or interconnection or wiring) near layer)))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/03/05 16:16
L18	15187	(257/59.ccls. or 257/66. ccls. or 257/72.ccls. or 257/E27.111.ccls. or 257/E29.278.ccls. or 257/E29.293.ccls. or 257/347.ccls. or 257/350.ccls. or 257/351.ccls. or 257/351.ccls. or 257/E29.275.ccls.)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/03/05 17:40
L19	36	(257/59.ccls. or 257/66. ccls. or 257/72.ccls. or 257/E27.111.ccls. or 257/E29.278.ccls. or 257/E29.293.ccls. or 257/347.ccls. or 257/350.ccls. or 257/351.ccls. or 257/351.ccls. or 257/E29.275.ccls.) and ((channel near2 (region or portion or area)) same (gate near2 (wire or wiring or metal or interconnect or interconnection)) same (tft or (thin near film near transistor)) same (gate adj electrode) same (drive or driving or driver) same pixel)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/03/05 17:40

| L20 | 89 | (257/59.ccls. or 257/66. ccls. or 257/72.ccls. or 257/E27.111.ccls. or 257/E29.278.ccls. or 257/E29.293.ccls. or 257/347.ccls. or 257/350.ccls. or 257/351.ccls. or 257/351.ccls. or 257/E29.275.ccls.) and (((channel near2 (region or portion or area)) same (gate near2 (wire or wiring or metal or interconnect or interconnection)) same (tft or (thin near film near transistor)) same (gate adj electrode) same (drive or driving or driver) same pixel) or ((gate near (wire or wiring or metal or interconnect or interconnection)) same electrode same (storage near capacitor) same ((conductive or conducting or metal or interconnect or interconnection or wiring) near layer))) | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2008/03/05 17:41 |

3/5/08 5:45:38 PM
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